INTEGRATED CIRCUITS

DATA SHEET

74ALVT16646
2.5V/3.3V 16-bus transceiver (3-State)

Product specification
Supersedes data of 1996 Aug 13
IC23 Data Handbook

1998 Feb 13

Philips
Semiconductors

PHILIPS

FEATURES

- 16-bit universal bus interface
- 5V I/O Compatible
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- No bus current loading when output is tied to 5V bus
- Power-up reset
- Power-up 3-State
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

DESCRIPTION

The 74ALVT16646 is a high-performance BiCMOS product designed for V_{CC} operation at 2.5V or 3.3V with I/O compatibility up to 5V.

This device is a 16-bit transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features an Output Enable ($\overline{OE}$) input for easy cascading and a Direction (DIR) input for direction control.

Data on the A or B bus is clocked into the registers on the Low to High transition of the appropriate clock (CPAB or CPBA). The select-control (SAB and SBA) inputs can multiplex stored and real-time (transparent mode data).

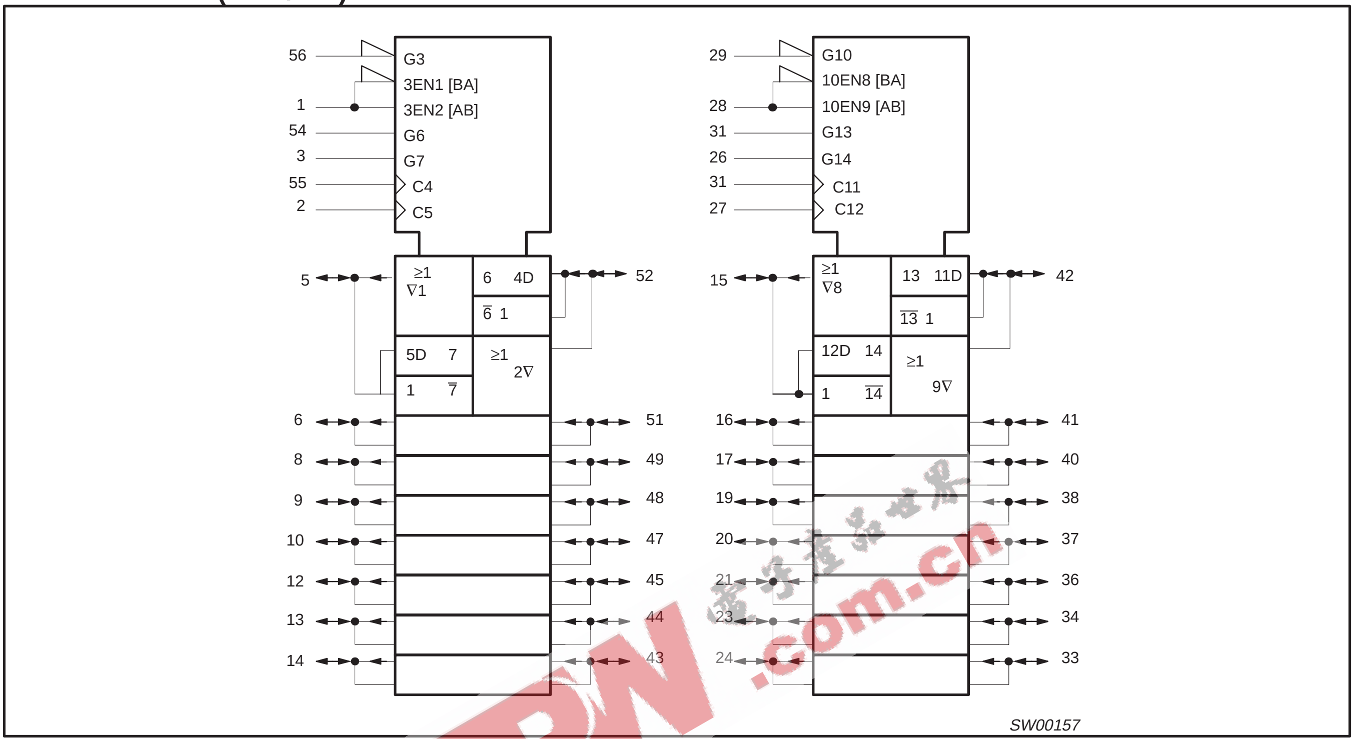
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T_{amb} = 25°C	TYPICAL		UNIT
			2.5V	3.3V	
t_{PLH} t_{PHL}	Propagation delay nAx to nBx or nBx to nAx	C_L = 50pF	2.2 2.3	1.7 1.8	ns
C_{IN}	Input capacitance DIR, $\overline{OE}$	V_I = 0V or V_{CC}	3	3	pF
$C_{I/O}$	I/O pin capacitance	$V_{I/O}$ = 0V or V_{CC}	9	9	pF
I_{CCZ}	Total supply current	Outputs disabled	40	70	µA

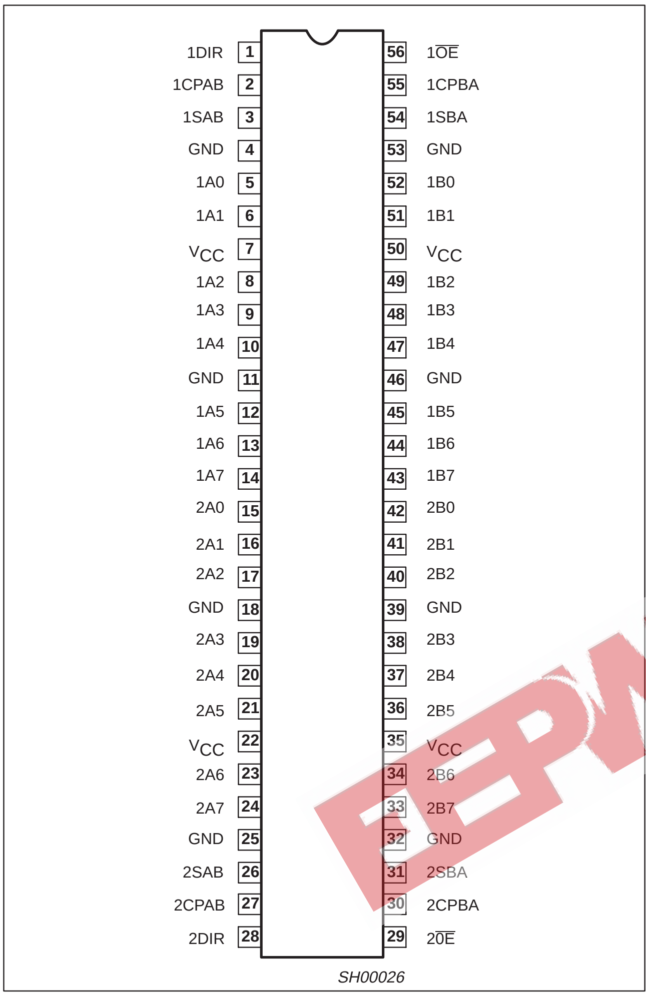
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
56-Pin Plastic SSOP Type III	–40°C to +85°C	74ALVT166646 DL	AV16646 DL	SOT371-1
56-Pin Plastic TSSOP Type II	–40°C to +85°C	74ALVT16646 DGG	AV16646 DGG	SOT364-1

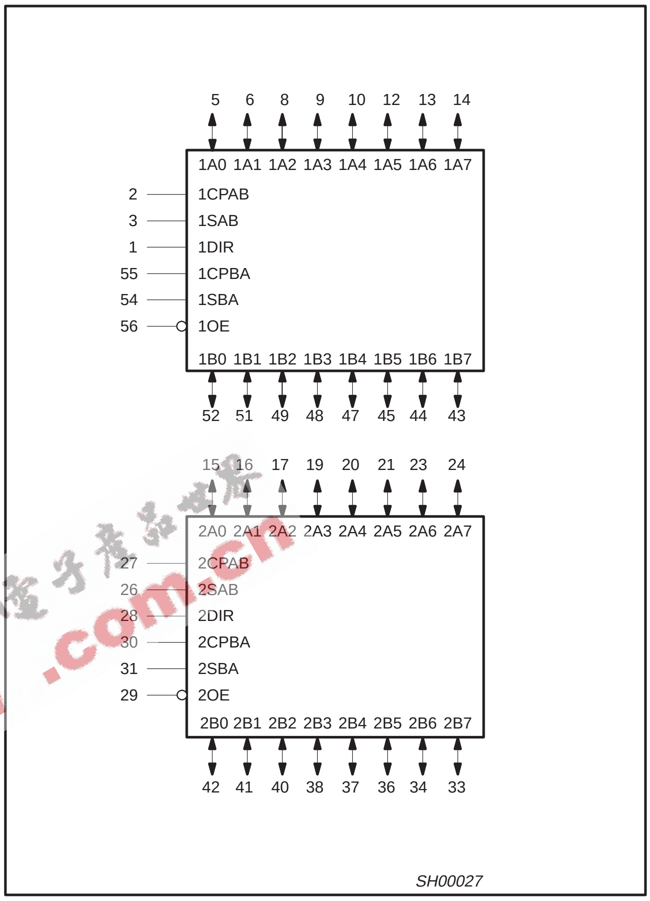
LOGIC SYMBOL (IEEE/IEC)



PIN CONFIGURATION



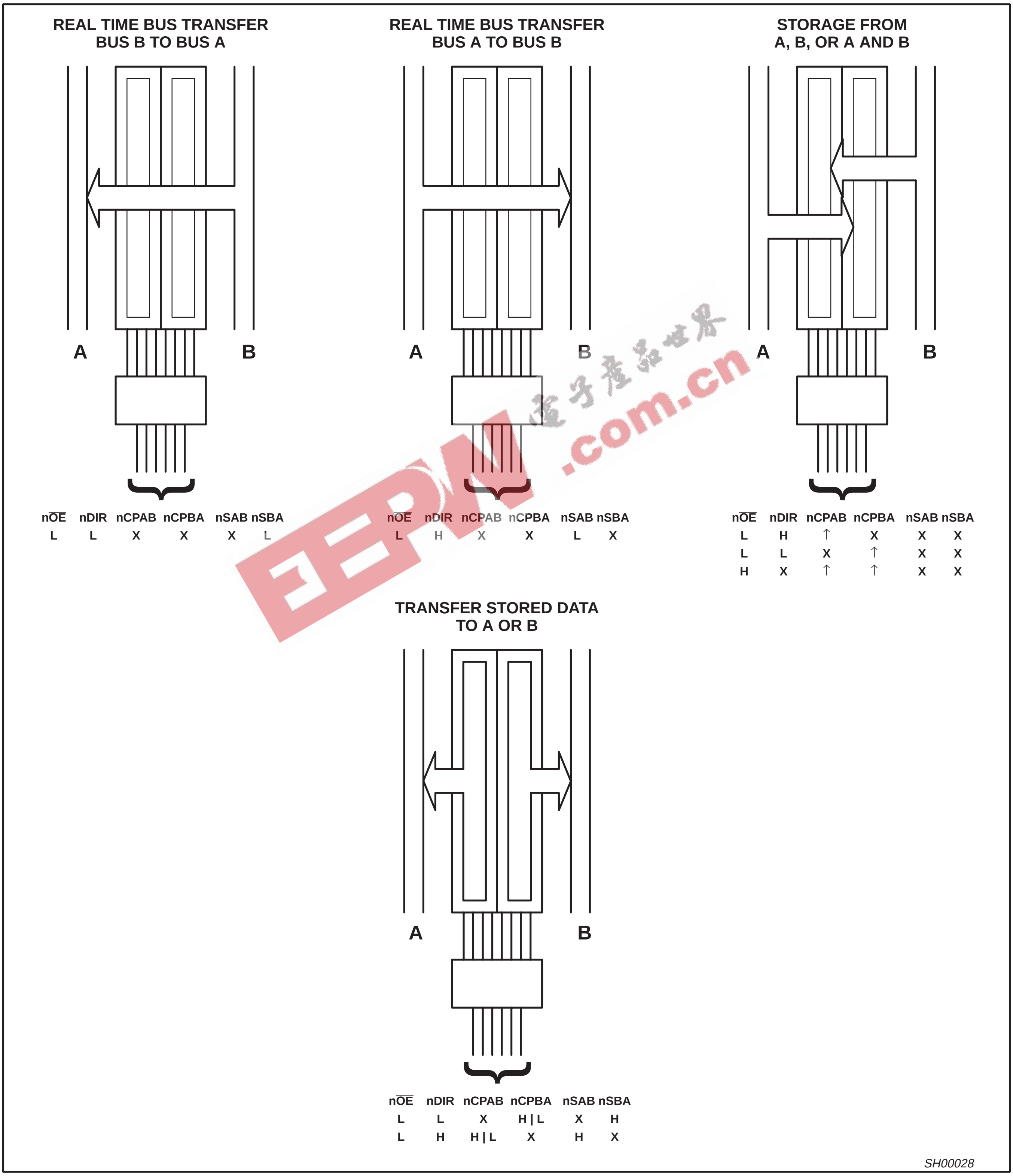
LOGIC SYMBOL



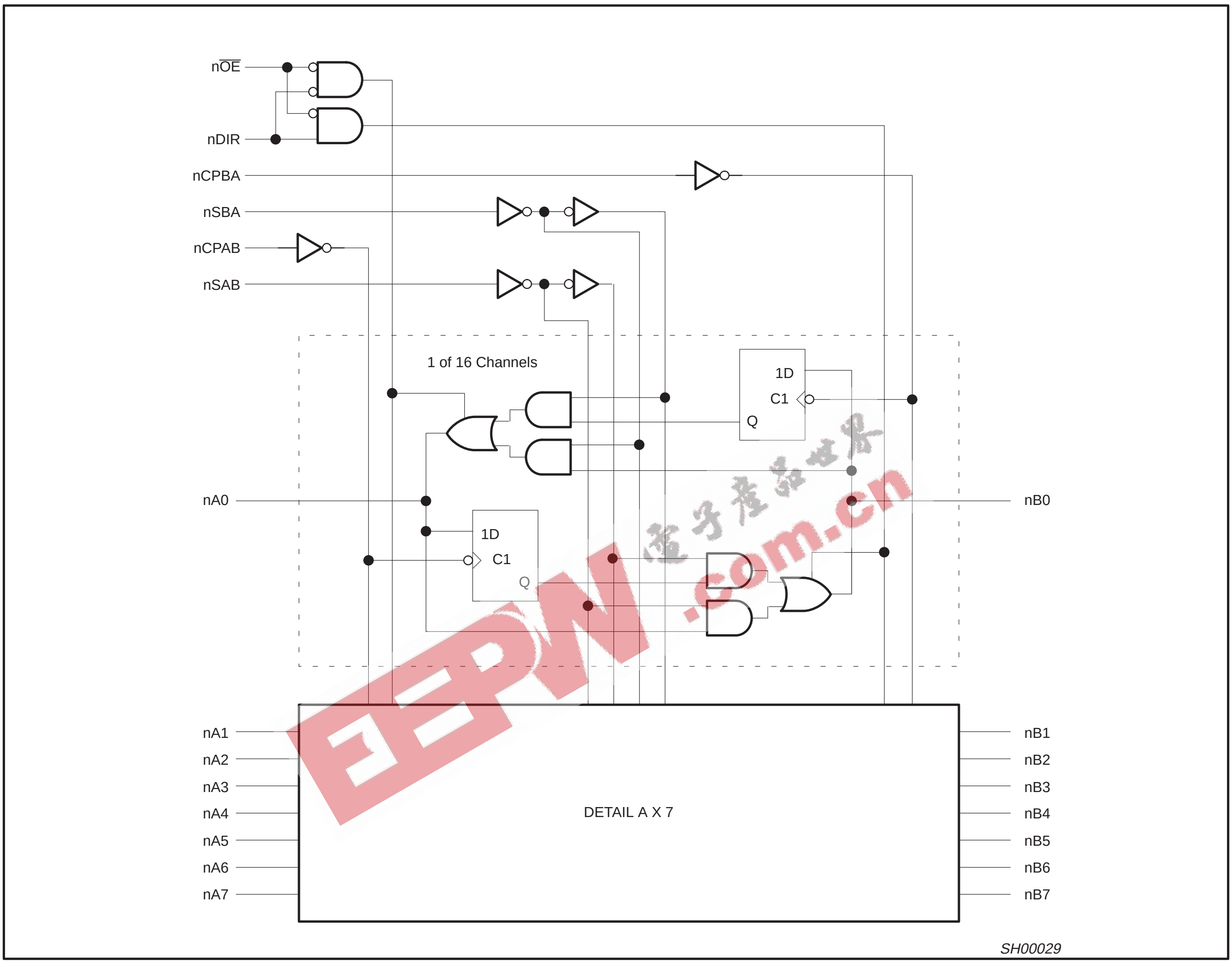
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
2, 55, 27, 30	1CPAB, 1CPBA, 2CPAB, 2CPBA	Clock input A to B / Clock input B to A
3, 54, 26, 31	1SAB, 1SBA, 2SAB, 2SBA	Select input A to B / Select input B to A
1, 28	1DIR, 2DIR	Direction control inputs
5, 6, 8, 9, 10, 12, 13, 14 15, 16, 17, 19, 20, 21, 23, 24	1A0 - 1A7, 2A0 - 2A7	Data inputs/outputs (A side)
52, 51, 49, 48, 47, 45, 44, 43 42, 41, 40, 38, 37, 36, 34, 33	1B0 - 1B7, 2B0 - 2B7	Data inputs/outputs (B side)
56, 29	$1\overline{OE}$, $2\overline{OE}$	Output enable inputs
4, 11, 18, 25, 32, 39, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V_{CC}	Positive supply voltage

The following examples demonstrate the four fundamental bus-management functions that can be performed with the 74ALVT16646.



LOGIC DIAGRAM



FUNCTION TABLE

INPUTS						DATA I/O		OPERATING MODE
nOE	nDIR	nCPAB	nCPBA	nSAB	nSBA	nAx	nBx	
X	X	↑	X	X	X	Input	Unspecified output*	Store A, B unspecified
X	X	X	↑	X	X	Unspecified output*	Input	Store B, A unspecified
H H	X X	↑ H or L	↑ H or L	X X	X X	Input	Input	Store A and B data Isolation, hold storage
L L	L L	X X	X H or L	X X	L H	Output	Input	Real time B data to A bus Stored B data to A bus
L L	H H	X H or L	X X	L H	X X	Input	Output	Real time A data to B bus Stored A data to B bus

H = High voltage level
L = Low voltage level
X = Don't care
↑ = Low-to-High clock transition
* The data output function may be enabled or disabled by various signals at the nOE input. Data input functions are always enabled, i.e., data at the bus pins will be stored on every Low-to-High transition of the clock.

ABSOLUTE MAXIMUM RATINGS[1, 2]

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		–0.5 to +4.6	V
I_{IK}	DC input diode current	$V_I < 0$	–50	mA
V_I	DC input voltage[3]		–0.5 to +7.0	V
I_{OK}	DC output diode current	$V_O < 0$	–50	mA
V_{OUT}	DC output voltage[3]	Output in Off or High state	–0.5 to +7.0	V
I_{OUT}	DC output current	Output in Low state	128	mA
		Output in High state	–64	
T_{stg}	Storage temperature range		–65 to +150	°C

NOTES:
1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	2.5V RANGE LIMITS		3.3V RANGE LIMITS		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	DC supply voltage	2.3	2.7	3.0	3.6	V
V_I	Input voltage	0	5.5	0	5.5	V
V_{IH}	High-level input voltage	1.7		2.0		V
V_{IL}	Input voltage		0.7		0.8	V
I_{OH}	High-level output current		–8		–32	mA
I_{OL}	Low-level output current		8		32	mA
	Low-level output current; current duty cycle ≤ 50%; f ≥ 1kHz		24		64	
$\Delta t/\Delta v$	Input transition rise or fall rate; Outputs enabled		10		10	ns/V
T_{amb}	Operating free-air temperature range	–40	+85	–40	+85	°C

DC ELECTRICAL CHARACTERISTICS (3.3V ±0.3V RANGE)

SYMBOL	PARAMETER	TEST CONDITIONS		LIMITS Temp = -40°C to +85°C MIN	TYP[1]	MAX	UNIT
V_{IK}	Input clamp voltage	V_{CC} = 3.0V; I_{IK} = –18mA			–0.85	–1.2	V
V_{OH}	High-level output voltage	V_{CC} = 3.0 to 3.6V; I_{OH} = –100µA		V_{CC}–0.2	V_{CC}		V
		V_{CC} = 3.0V; I_{OH} = –32mA		2.0	2.3		
V_{OL}	Low–level output voltage	V_{CC} = 3.0V; I_{OL} = 100µA			0.07	0.2	V
		V_{CC} = 3.0V; I_{OL} = 16mA			0.25	0.4	
		V_{CC} = 3.0V; I_{OL} = 32mA			0.3	0.5	
		V_{CC} = 3.0V; I_{OL} = 64mA			0.4	0.55	
V_{RST}	Power-up output low voltage[6]	V_{CC} = 3.6V; I_O = 1mA; V_I = V_{CC} or GND				0.55	V
I_I	Input leakage current	V_{CC} = 3.6V; V_I = V_{CC} or GND	Control pins		0.1	±1	µA
		V_{CC} = 0 or 3.6V; V_I = 5.5V	Control pins		0.1	10	
		V_{CC} = 3.6V; V_I = 5.5V	I/O Data pins[4]		0.1	20	
		V_{CC} = 3.6V; V_I = V_{CC}	I/O Data pins[4]		0.5	10	
		V_{CC} = 3.6V; V_I = 0	I/O Data pins[4]		0.1	-5	
I_{OFF}	Off current	V_{CC} = 0V; V_I or V_O = 0 to 4.5V			0.1	±100	µA
I_{HOLD}	Bus Hold current Data inputs[7]	V_{CC} = 3V; V_I = 0.8V		75	130		µA
		V_{CC} = 3V; V_I = 2.0V		–75	–140		µA
		V_{CC} = 3.0V; V_I = 0V to 3.6V		±500			µA
I_{EX}	Current into an output in the High state when V_O > V_{CC}	V_O = 5.5V; V_{CC} = 3.0V			50	125	µA
$I_{PU/PD}$	Power up/down 3-State output current[3]	$V_{CC} \leq$ 1.2V; V_O = 0.5V to V_{CC}; V_I = GND or V_{CC}; OE/$\overline{OE}$ = Don't care			40	±100	µA
I_{CCH}	Quiescent supply current	V_{CC} = 3.6V; Outputs High, V_I = GND or $V_{CC,}$ I_O = 0			0.07	0.14	mA
I_{CCL}		V_{CC} = 3.6V; Outputs Low, V_I = GND or $V_{CC,}$ I_O = 0			3.2	7	
I_{CCZ}		V_{CC} = 3.6V; Outputs Disabled; V_I = GND or $V_{CC,}$ I_O = 0[5]			0.07	0.14	
ΔI_{CC}	Additional supply current per input pin[2]	V_{CC} = 3V to 3.6V; One input at V_{CC}–0.6V, Other inputs at V_{CC} or GND			0.04	0.4	mA

NOTES:
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
2. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
3. This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
4. Unused pins at V_{CC} or GND.
5. I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground.
6. For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.
7. This is the bus hold overdrive current required to force the input to the opposite logic state.

AC CHARACTERISTICS (3.3V ±0.3V RANGE)

GND = 0V; $t_R = t_F$ = 2.5ns; C_L = 50pF; R_L = 500Ω; T_{amb} = –40°C to +85°C.

SYMBOL	PARAMETER	WAVEFORM	LIMITS			UNIT
			V_{CC} = 3.3V ±0.3V			
			MIN	TYP[1]	MAX	
f_{MAX}	Maximum clock frequency	1	150			MHz
t_{PLH} t_{PHL}	Propagation delay nCPAB to nBx or nCPBA to nAx	1	1.0 1.0	2.6 2.1	3.7 3.1	ns
t_{PLH} t_{PHL}	Propagation delay nSAB to nBx or nSBA to nAx	2	1.0 1.0	2.4 2.1	4.0 3.8	ns
t_{PLH} t_{PHL}	Propagation delay nAx to nBx or nBx to nAx	2 3	0.5 0.5	1.7 1.8	2.4 2.8	ns
t_{PZH} t_{PZL}	Output enable time to High and Low level	5 6	0.5 0.5	2.3 2.0	3.9 4.4	ns
t_{PHZ} t_{PLZ}	Output disable time from High and Low Level	5 6	1.5 1.5	3.4 2.8	5.0 4.2	ns
t_{PZH} t_{PZL}	Output enable time nDIR to nAx or nBx	5 6	1.0 0.5	2.8 2.2	5.0 4.7	ns
t_{PHZ} t_{PLZ}	Output disable time nDIR to nAx or nBx	5 6	1.5 1.0	3.5 3.1	5.4 4.7	ns

NOTE:
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC SETUP REQUIREMENTS (3.3V ±0.3V RANGE)

GND = 0V; $t_R = t_F$ = 2.5ns; C_L = 50pF; R_L = 500Ω; T_{amb} = –40°C to +85°C.

SYMBOL	PARAMETER	WAVEFORM	LIMITS		UNIT
			V_{CC} = 3.3V ±0.3V		
			MIN	TYP[1]	
$t_S(H)$ $t_S(L)$	Setup time, High or Low nAx to nCPAB or nBx to nCPBA	4	1.6 1.6	1.0 1.0	ns
$t_h(H)$ $t_h(L)$	Hold time, High or Low nAx to nCPAB or nBx or nCPBA	4	0.0 0.0	–0.5 –0.7	ns
$t_w(H)$ $t_w(L)$	Pulse width, High or Low nCPAB or nCPBA	1	1.5 1.5		ns

NOTE:
1. This data sheet limit may vary among suppliers.

DC ELECTRICAL CHARACTERISTICS (2.5V ±0.2V RANGE)

SYMBOL	PARAMETER	TEST CONDITIONS		LIMITS Temp = -40°C to +85°C MIN	TYP[1]	MAX	UNIT
V_{IK}	Input clamp voltage	V_{CC} = 2.3V; I_{IK} = –18mA			–0.85	–1.2	V
V_{OH}	High-level output voltage	V_{CC} = 2.3 to 3.6V; I_{OH} = –100µA		V_{CC}–0.2	V_{CC}		V
		V_{CC} = 2.3V; I_{OH} = –8mA		1.8	2.1		
V_{OL}	Low-level output voltage	V_{CC} = 2.3V; I_{OL} = 100µA			0.07	0.2	V
		V_{CC} = 2.3V; I_{OL} = 24mA			0.3	0.5	
		V_{CC} = 2.3V; I_{OL} = 8mA				0.4	
V_{RST}	Power-up output low voltage[7]	V_{CC} = 2.7V; I_O = 1mA; V_I = V_{CC} or GND				0.55	V
I_I	Input leakage current	V_{CC} = 2.7V; V_I = V_{CC} or GND	Control pins		0.1	±1	µA
		V_{CC} = 0 or 2.7V; V_I = 5.5V			0.1	10	
		V_{CC} = 2.7V; V_I = 5.5V	I/O Data pins[4]		0.1	20	
		V_{CC} = 2.7V; V_I = V_{CC}			0.1	10	
		V_{CC} = 2.7V; V_I = 0			0.1	-5	
I_{OFF}	Off current	V_{CC} = 0V; V_I or V_O = 0 to 4.5V			0.1	±100	µA
I_{HOLD}	Bus Hold current	V_{CC} = 2.3V; V_I = 0.7V			90		µA
	A or B inputs[6]	V_{CC} = 2.3V; V_I = 1.7V			–10		µA
I_{EX}	Current into an output in the High state when $V_O > V_{CC}$	V_O = 5.5V; V_{CC} = 2.3V			50	125	µA
$I_{PU/PD}$	Power up/down 3-State output current[3]	$V_{CC} \leq$ 1.2V; V_O = 0.5V to V_{CC}; V_I = GND or V_{CC}; OE/$\overline{OE}$ = Don't care			40	100	µA
I_{CCH}	Quiescent supply current	V_{CC} = 2.7V; Outputs High, V_I = GND or V_{CC}, I_O = 0			0.04	0.1	mA
I_{CCL}		V_{CC} = 2.7V; Outputs Low, V_I = GND or V_{CC}, I_O = 0			2.3	4.5	
I_{CCZ}		V_{CC} = 2.7V; Outputs Disabled; V_I = GND or V_{CC}, I_O = 0[5]			0.04	0.1	
ΔI_{CC}	Additional supply current per input pin[2]	V_{CC} = 2.3V to 2.7V; One input at V_{CC}–0.6V, Other inputs at V_{CC} or GND			0.01	0.4	mA

NOTES:
1. All typical values are at V_{CC} = 2.5V and T_{amb} = 25°C.
2. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
3. This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 2.5V ± 0.2V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
4. Unused pins at V_{CC} or GND.
5. I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground.
6. Not guaranteed.
7. For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.

AC CHARACTERISTICS (2.5V ±0.2V RANGE)

GND = 0V; $t_R = t_F$ = 2.5ns; C_L = 50pF; R_L = 500Ω; T_{amb} = –40°C to +85°C.

SYMBOL	PARAMETER	WAVEFORM	LIMITS			UNIT
			V_{CC} = 2.5V ±0.2V			
			MIN	TYP[1]	MAX	
f_{MAX}	Maximum clock frequency	1	150			MHz
t_{PLH} t_{PHL}	Propagation delay nCPAB to nBx or nCPBA to nAx	1	1.0 1.0	3.2 2.8	4.8 4.2	ns
t_{PLH} t_{PHL}	Propagation delay nSAB to nBx or nSBA to nAx	2	1.5 1.5	3.4 3.4	5.8 6.0	ns
t_{PLH} t_{PHL}	Propagation delay nAx to nBx or nBx to nAx	2 3	0.5 0.5	2.2 2.3	3.2 3.8	ns
t_{PZH} t_{PZL}	Output enable time to High and Low level	5 6	1.5 1.0	3.4 2.7	5.8 6.0	ns
t_{PHZ} t_{PLZ}	Output disable time from High and Low Level	5 6	1.5 1.0	3.2 2.5	5.2 3.7	ns
t_{PZH} t_{PZL}	Output enable time nDIR to nAx or nBx	5 6	2.0 1.0	4.1 2.5	7.0 4.1	ns
t_{PHZ} t_{PLZ}	Output disable time nDIR to nAx or nBx	5 6	1.5 1.0	3.9 3.1	6.1 4.9	ns

NOTE:
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

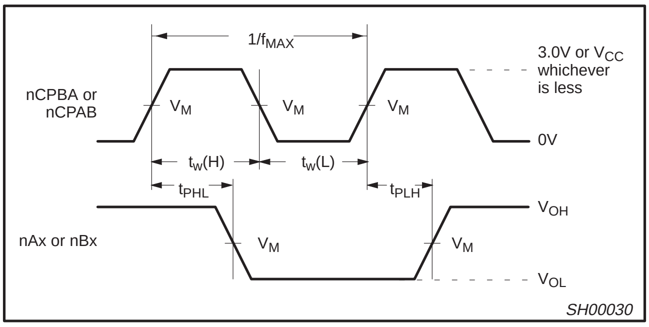
AC SETUP REQUIREMENTS (2.5V ±0.2V RANGE)

GND = 0V; $t_R = t_F$ = 2.5ns; C_L = 50pF; R_L = 500Ω; T_{amb} = –40°C to +85°C.

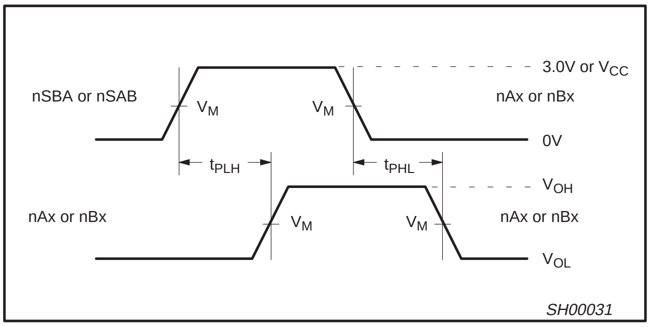
SYMBOL	PARAMETER	WAVEFORM	LIMITS		UNIT
			V_{CC} = 2.5V ±0.2V		
			MIN	TYP	
t_S(H) t_S(L)	Setup time, High or Low nAx to nCPAB or nBx to nCPBA	4	2.0 2.0	1.2 1.2	ns
t_h(H) t_h(L)	Hold time, High or Low nAx to nCPAB or nBx or nCPBA	4	0.0 0.0	–1.0 –1.0	ns
t_w(H) t_w(L)	Pulse width, High or Low nCPAB or nCPBA	1	1.5 1.5		ns

AC WAVEFORMS

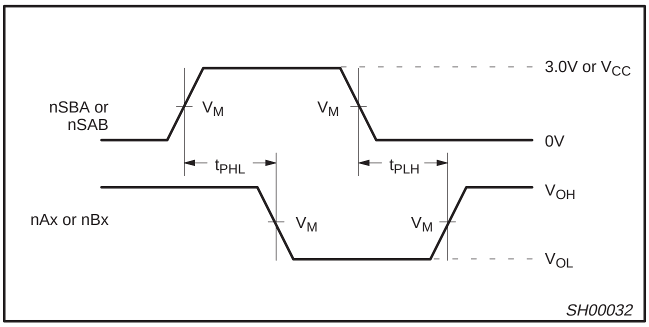
V_M = 1.5V at V_{CC} ≥ 3.0V; $V_M = V_{CC}/2$ at V_{CC} ≤ 2.7V
$V_X = V_{OL}$ + 0.3V at V_{CC} ≥ 3.0V; $V_X = V_{OL}$ + 0.15V at V_{CC} ≤ 2.7V
$V_Y = V_{OH}$ – 0.3V at V_{CC} ≥ 3.0V; $V_Y = V_{OH}$ – 0.15V at V_{CC} ≤ 2.7V



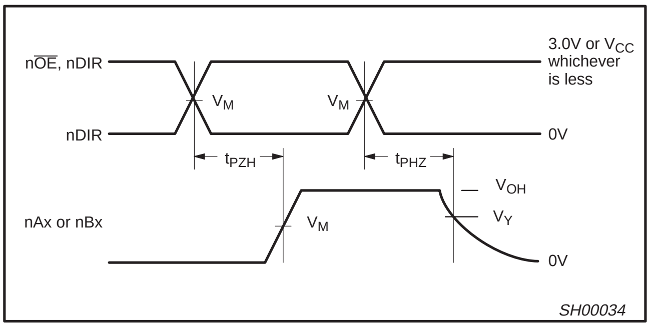
Waveform 1. Propagation Delay, Clock Input to Output, Clock Pulse Width, and Maximum Clock Frequency



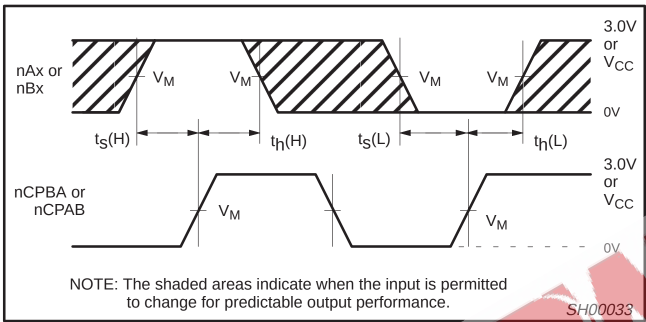
Waveform 2. Propagation Delay, nSAB to nBx or nSBA to nAx, nAx to nBx or nBx to nAx



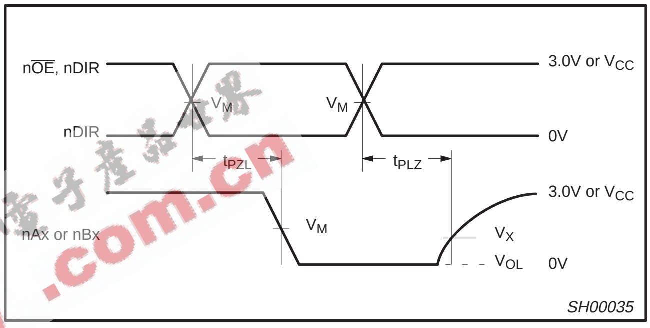
Waveform 3. Propagation Delay, nSBA to nAx or nSAB to nBx



Waveform 5. 3–State Output Enable Time to High Level and Output Disable Time from High Level

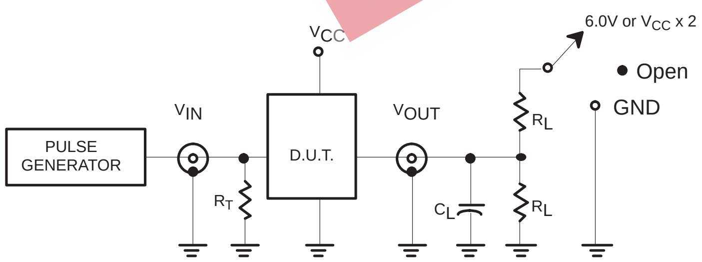


Waveform 4. Data Setup and Hold Times

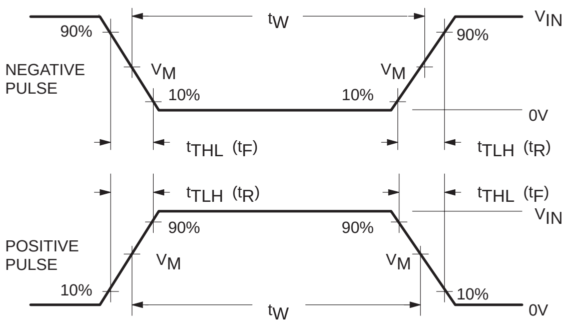


Waveform 6. 3–State Output Enable Time to Low Level and Output Disable Time from Low Level

TEST CIRCUIT AND WAVEFORMS



Test Circuit for 3-State Outputs



SWITCH POSITION

TEST	SWITCH
t_{PLZ}/t_{PZL}	6V or V_{CC} x 2
t_{PLH}/t_{PHL}	Open
t_{PHZ}/t_{PZH}	GND

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

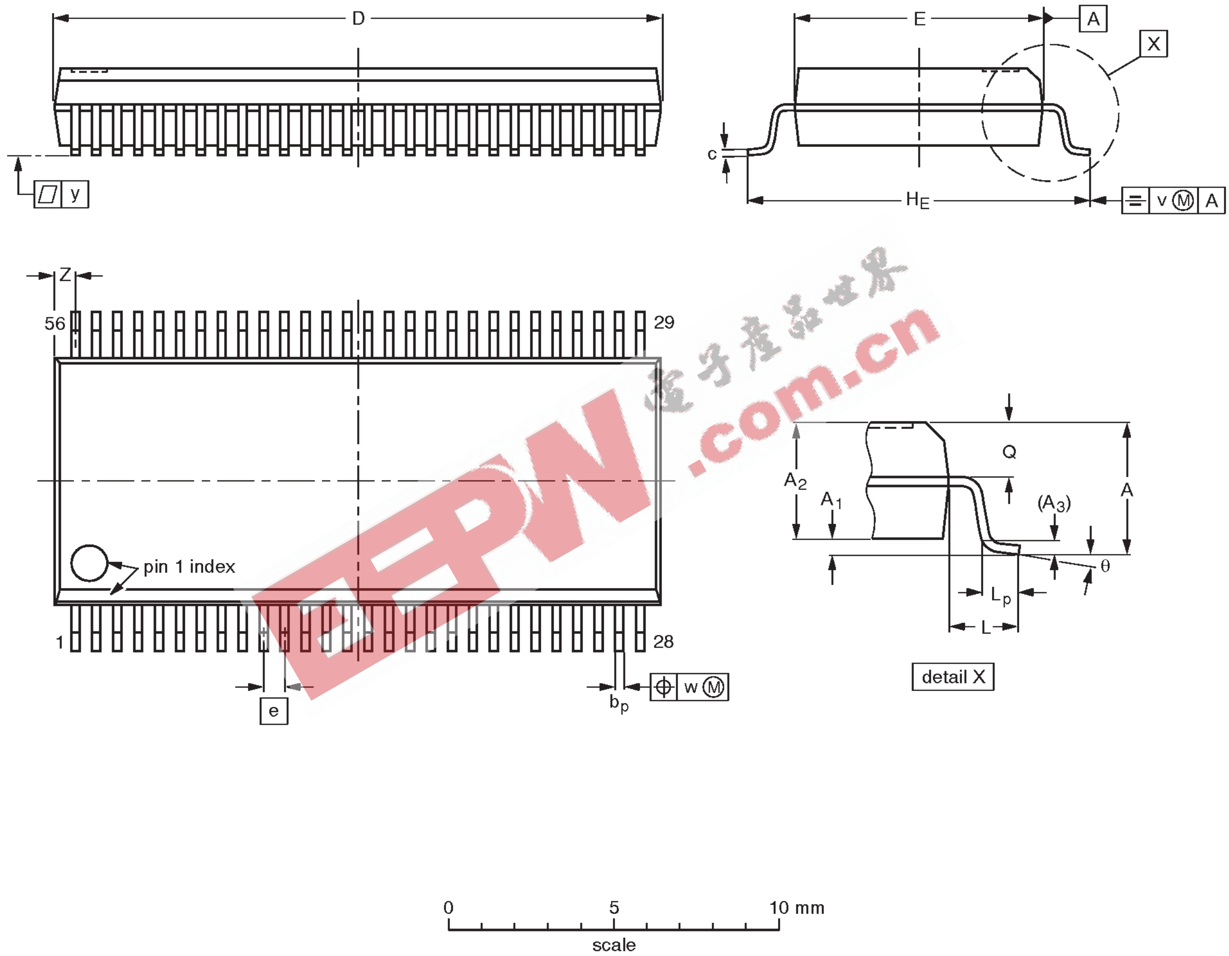
C_L = Load capacitance includes jig and probe capacitance: See AC CHARACTERISTICS for value.

R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

FAMILY	INPUT PULSE REQUIREMENTS				
	Amplitude	Rep. Rate	t_W	t_R	t_F
74ALVT16	3.0V or V_{CC} whichever is less	≤ 10MHz	500ns	≤ 2.5ns	≤ 2.5ns

SW00025

SSOP56: plastic shrink small outline package; 56 leads; body width 7.5 mm **SOT371-1**



DIMENSIONS (mm are the original dimensions)

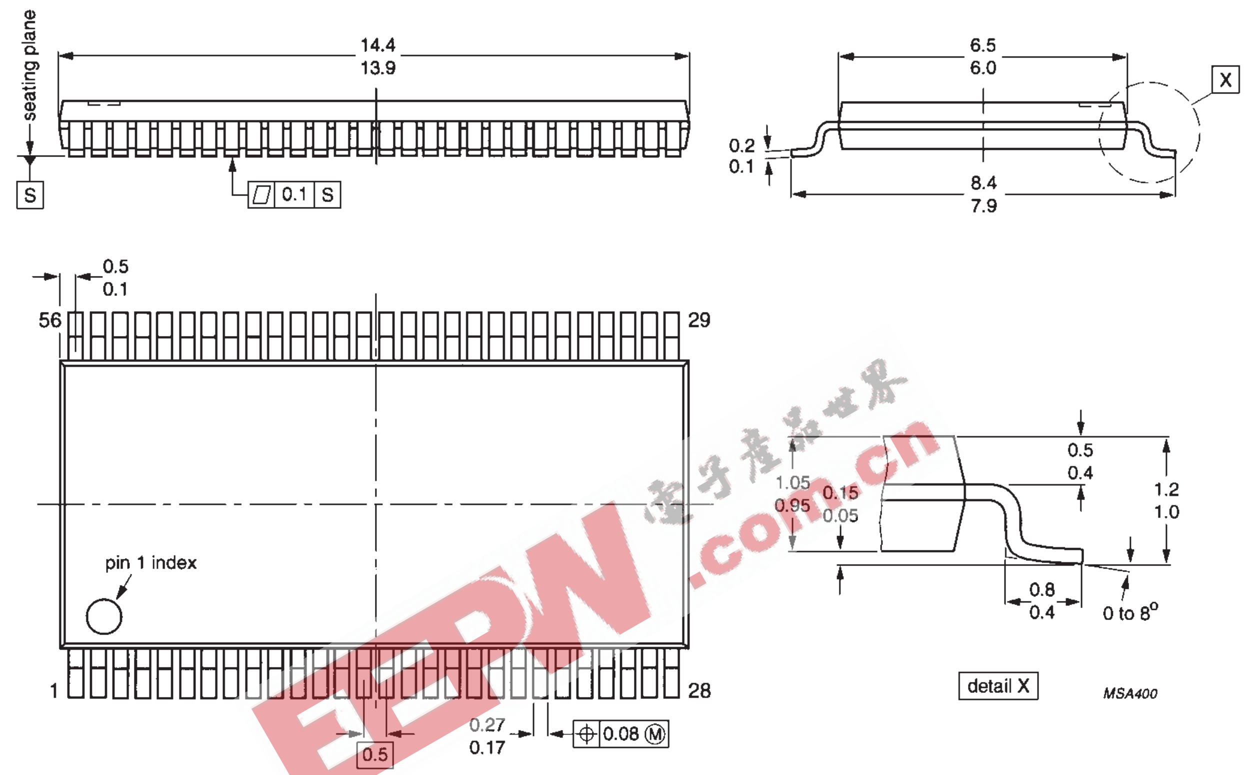
UNIT	A max.	A_1	A_2	A_3	b_p	c	D (1)	E (1)	e	H_E	L	L_p	Q	v	w	y	Z (1)	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	18.55 18.30	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT371-1		MO-118AB				~~93-11-02~~ 95-02-04

TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1mm **SOT364-1**



Dimensions in mm.

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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